BLF6G27-45; BLF6G27S-45

WiMAX power LDMOS transistor

AMPLEON

Rev. 5 — 1 September 2015

Product data sheet

Product profile 1.

1.1 General description

45 W LDMOS power transistor for base station applications at frequencies from 2500 MHz to 2700 MHz.

Typical performance

RF performance at $T_{case} = 25$ °C in a class-AB production test circuit.

Mode of operation	f (MHz)	V _{DS} (V)	P _{L(AV)} (W)	G _p (dB)	•-	ACPR _{885k} (dBc)	ACPR _{1980k} (dBc)
1-carrier N-CDMA[1]	2500 to 2700	28	7	18	24	-49 <mark>[2]</mark>	-64 <mark>2</mark>

Single carrier N-CDMA with pilot, paging sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on CCDF. Channel bandwidth is 1.23 MHz.

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features and benefits

- Typical 1-carrier N-CDMA performance (single carrier N-CDMA with pilot, paging, sync and 6 traffic channels [Walsh codes 8 - 13]. PAR = 9.7 dB at 0.01 % probability on CCDF. Channel bandwidth is 1.23 MHz), a supply voltage of 28 V and an I_{Dq} of 350 mA:
- Qualified up to a maximum V_{DS} operation of 32 V
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation
- Internally matched for ease of use
- Low gold plating thickness on leads
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

^[2] Measured within 30 kHz bandwidth.

1.3 Applications

■ RF power amplifiers for base stations and multi carrier applications in the 2500 MHz to 2700 MHz frequency range

2. Pinning information

Table 2. Pinning

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<u>[1]</u> 3	2 —
2	- 3 sym112

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BLF6G27-45	-	flanged ceramic package; 2 mounting holes; 2 leads	SOT608A			
BLF6G27S-45	-	ceramic earless flanged package; 2 leads	SOT608B			

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

V_{DS} drain-source voltage - 65 V_{GS} gate-source voltage -0.5 +13	Unit
V _{GS} gate-source voltage -0.5 +13	V
	V
I _D drain current - 20	Α
T_{stg} storage temperature -65 +150	°C
T _j junction temperature - 200	°C

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5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Туре	Тур	Unit
$R_{\text{th(j-case)}}$	thermal resistance from	T _{case} = 80 °C;	BLF6G27-45	1.7	K/W
	junction to case	$P_L = 34 \text{ W (CW)}$	BLF6G27S-45	1.7	K/W

6. Characteristics

Table 6. Characteristics

 $T_i = 25$ °C per section; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.5 \text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 60 mA	1.4	1.9	2.4	V
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-	-	1.4	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 V;$ $V_{DS} = 10 V$	8.8	10.4	-	Α
I _{GSS}	gate leakage current	$V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	140	nA
g _{fs}	forward transconductance	$V_{DS} = 10 \text{ V}; I_{D} = 2.5 \text{ A}$	-	4.3	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 2.1 A$	-	0.24	0.385	Ω
C _{rs}	feedback capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V};$ f = 1 MHz	-	1.1	-	pF

7. Application information

Table 7. Application information

Mode of operation: Single carrier N-CDMA with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR 9.7 dB at 0.01 % probability on CCDF; channel bandwidth = 1.23 MHz; f = 2700 MHz; RF performance at $V_{DS} = 28$ V; $I_{Dq} = 350$ mA; $T_{case} = 25$ °C; unless otherwise specified; in a class-AB production circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$P_{L(AV)}$	average output power		-	7	-	W
Gp	power gain	$P_{L(AV)} = 7 W$	16.5	18	-	dB
RLin	input return loss	$P_{L(AV)} = 7 W$	-	-10	-5	dB
η_{D}	drain efficiency	$P_{L(AV)} = 7 W$	22	24	-	%
ACPR _{885k}	adjacent channel power ratio (885 kHz)	$P_{L(AV)} = 7 W$	[1] -	-49	-46	dBc
ACPR _{1980k}	adjacent channel power ratio (1980 kHz)	$P_{L(AV)} = 7 W$	[1] _	-64	-61	dBc

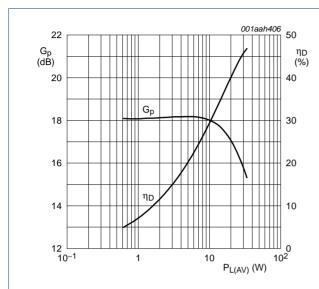
^[1] Measured within 30 kHz bandwidth.

7.1 Ruggedness in class-AB operation

The BLF6G27-45 and BLF6G27S-45 are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: $V_{DS} = 28 \text{ V}$; $I_{Dq} = 350 \text{ mA}$; $P_L = 45 \text{ W}$ (CW); f = 2600 MHz.

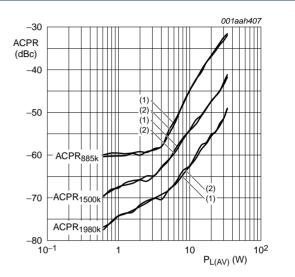
BLF6G27-45_BLF6G27S-45#5

7.2 Single carrier N-CDMA performance



 V_{DS} = 28 V; I_{Dq} = 350 mA; f = 2600 MHz; single carrier N-CDMA; PAR = 9.7 dB at 0.01 % probability; channel bandwidth = 1.23 MHz; instantaneous bandwidth = 30 kHz.

Fig 1. Power gain and drain efficiency as functions of average load power; typical values

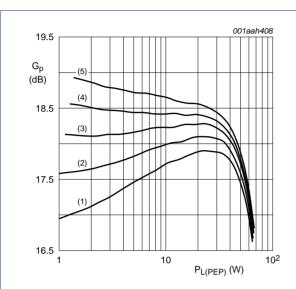


 V_{DS} = 28 V; I_{Dq} = 350 mA; f = 2600 MHz; single carrier N-CDMA; PAR = 9.7 dB at 0.01 % probability; channel bandwidth = 1.23 MHz; instantaneous bandwidth = 30 kHz.

- (1) Low frequency component
- (2) High frequency component

Fig 2. Adjacent channel power ratio as function of average load power; typical values

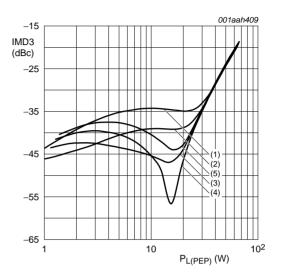
7.3 Two-tone



 V_{DS} = 28 V; f_1 = 2598.75 MHz; f_2 = 2601.25 MHz; 2.5 MHz tone spacing.

- (1) $I_{Dq} = 250 \text{ mA}$
- (2) $I_{Dq} = 300 \text{ mA}$
- (3) $I_{Dq} = 350 \text{ mA}$
- (4) $I_{Dq} = 400 \text{ mA}$
- (5) $I_{Dq} = 500 \text{ mA}$

Fig 3. Power gain as function of peak envelope load power; typical values

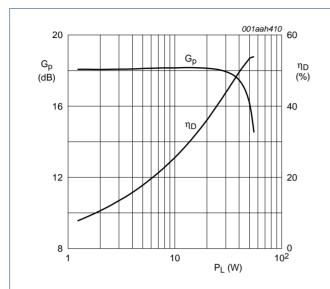


 V_{DS} = 28 V; f₁ = 2598.75 MHz; f₂ = 2601.25 MHz; 2.5 MHz tone spacing.

- (1) $I_{Dq} = 250 \text{ mA}$
- (2) $I_{Dq} = 300 \text{ mA}$
- (3) $I_{Dq} = 350 \text{ mA}$
- (4) $I_{Dq} = 400 \text{ mA}$
- (5) $I_{Dq} = 500 \text{ mA}$

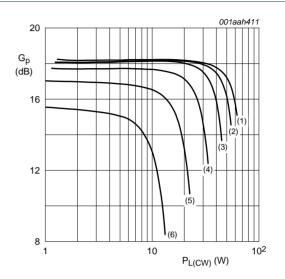
Fig 4. Third order intermodulation distortion as function of peak envelope load power; typical values

7.4 Continuous wave



 I_{Dq} = 350 mA; f = 2600 MHz; T_{case} = 25 °C; V_{DS} = 28 V.

Fig 5. Power gain and drain efficiency as functions of CW load power; typical values

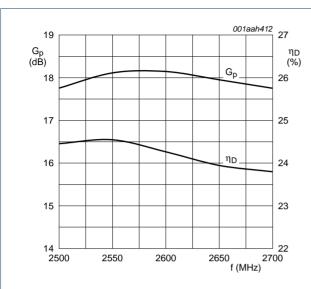


 I_{Dq} = 350 mA; f = 2600 MHz; T_{case} = 25 °C.

- (1) $V_{DS} = 32 V$
- (2) $V_{DS} = 28 \text{ V}$
- (3) $V_{DS} = 24 \text{ V}$
- (4) $V_{DS} = 20 \text{ V}$
- (5) $V_{DS} = 16 V$
- (6) $V_{DS} = 12 V$

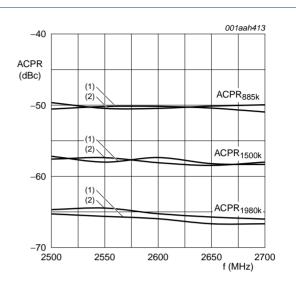
Fig 6. Power gain as function of CW load power; typical values

7.5 Single carrier N-CDMA broadband performance at 7 W average



 V_{DS} = 28 V; I_{Dq} = 350 mA; single carrier N-CDMA; PAR = 9.7 dB at 0.01 % probability; instantaneous bandwidth = 30 kHz.

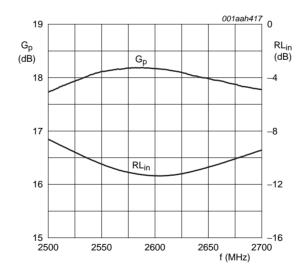
Fig 7. Power gain and drain efficiency as functions of frequency; typical values



 V_{DS} = 28 V; I_{Dq} = 350 mA; single carrier N-CDMA; PAR = 9.7 dB at 0.01 % probability; instantaneous bandwidth = 30 kHz.

- (1) Low frequency component
- (2) High frequency component

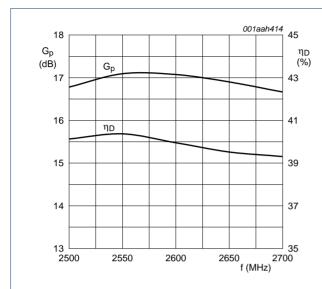
Fig 8. Adjacent channel power ratio as function of frequency; typical values



 V_{DS} = 28 V; I_{Dq} = 350 mA; single carrier N-CDMA; PAR = 9.7 dB at 0.01 % probability; instantaneous bandwidth = 30 kHz.

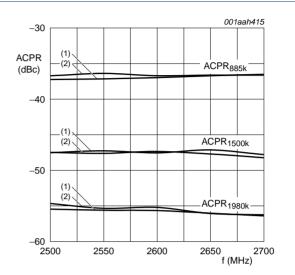
Fig 9. Power gain and input return loss as functions of frequency

7.6 Single carrier N-CDMA broadband performance at 20 W average



 V_{DS} = 28 V; I_{Dq} = 350 mA; single carrier N-CDMA; PAR = 9.7 dB at 0.01 % probability; instantaneous bandwidth = 30 kHz.

Fig 10. Power gain and drain efficiency as functions of frequency; typical values

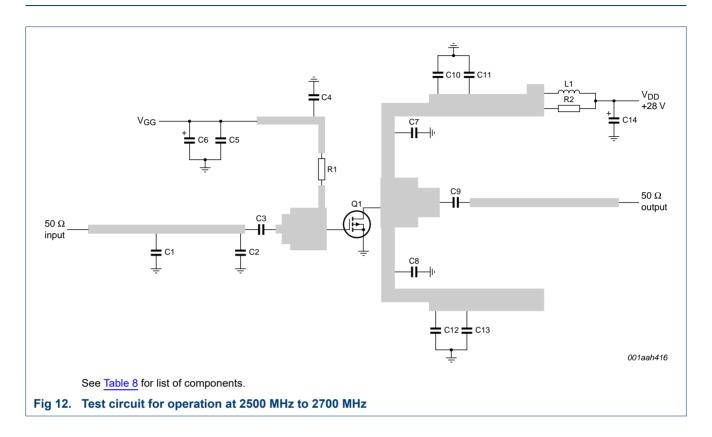


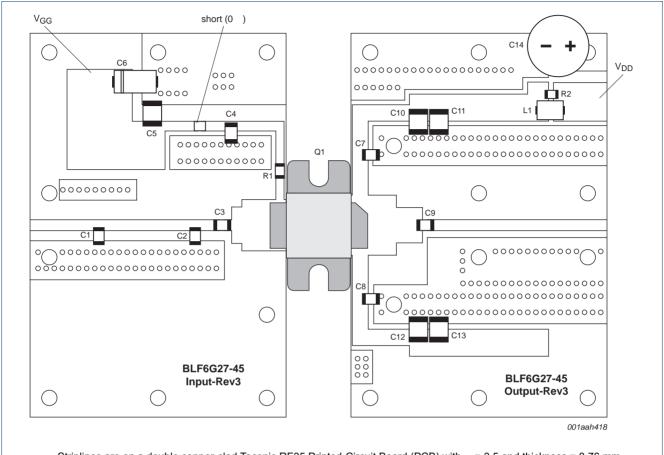
 V_{DS} = 28 V; I_{Dq} = 350 mA; single carrier N-CDMA; PAR = 9.7 dB at 0.01 % probability; instantaneous bandwidth = 30 kHz.

- (1) Low frequency component
- (2) High frequency component

Fig 11. Adjacent channel power ratio as function of frequency; typical values

8. Test information





Striplines are on a double copper-clad Taconic RF35 Printed-Circuit Board (PCB) with ε_r = 3.5 and thickness = 0.76 mm. See Table 8 for list of components.

Fig 13. Component layout for 2500 MHz to 2700 MHz test circuit

Table 8. List of components

For test circuit, see Figure 12 and Figure 13.

Component	Description	Value		Remarks
C1	multilayer ceramic chip capacitor	0.3 pF	[1]	
C2	multilayer ceramic chip capacitor	0.5 pF	[1]	
C3, C4, C7, C8	multilayer ceramic chip capacitor	11 pF	[1]	
C5, C10, C11, C12, C13	multilayer ceramic chip capacitor	4.7 μF		C4532X7R1H475M
C6	tantalum capacitor	10 μ F; 35 V		Kemet (Farnell)
C9	multilayer ceramic chip capacitor	8.2 pF		
C14	electrolytic capacitor	470 μF; 63 V		
L1	ferrite SMD bead	-		Ferroxcube BDS 3/3/4.6-4S2 or equivalent
R1	resistor	22 Ω		package 0603
R2	resistor	12 Ω		package 1206
Q1	BLF6G27-45 or BLF6G27S-45	-		

^[1] American Technical Ceramics type 100B or capacitor of same quality.

Table 9. Measured test circuit impedances

f	Zi	Z _o
(GHz)	(Ω)	(Ω)
2.50	11.1 – j11.0	18.4 – j9.1
2.55	10.6 – j10.8	16.9 – j9.2
2.60	10.1 – j10.5	15.6 – j9.2
2.65	9.6 – j10.2	14.4 – j9.1
2.70	9.1 – j9.8	13.3 – j8.9

9. Package outline

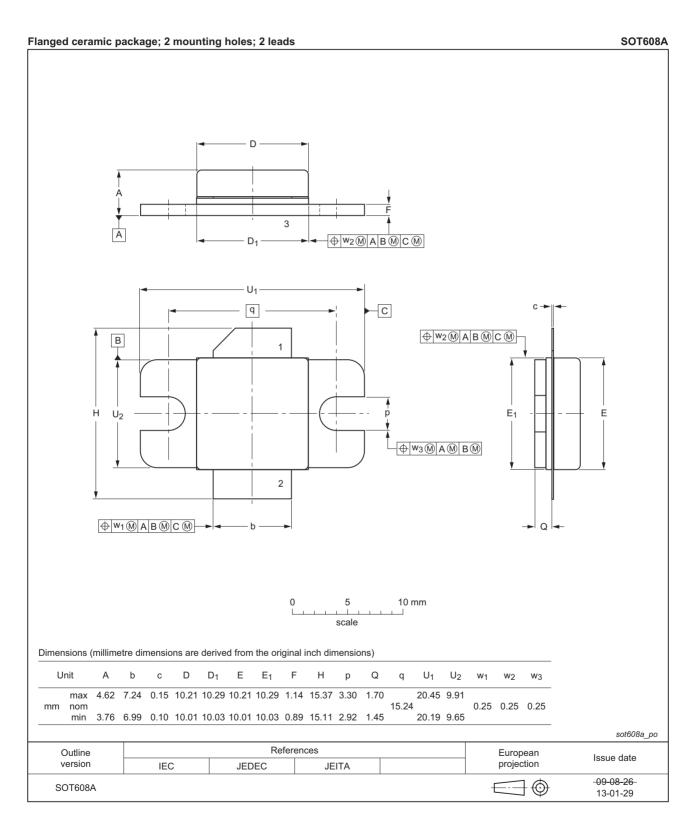


Fig 14. Package outline SOT608A

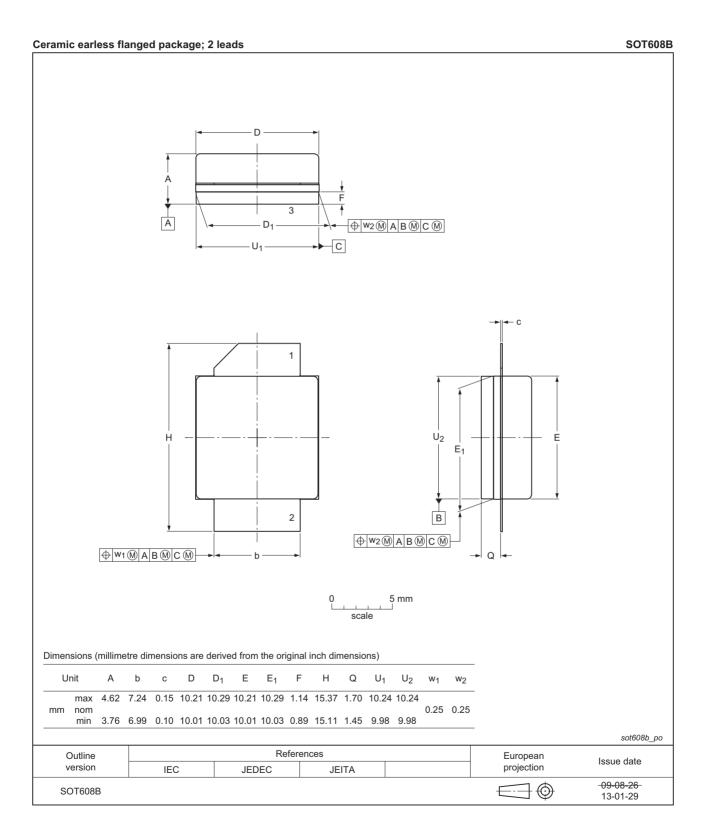


Fig 15. Package outline SOT608B

10. Abbreviations

Table 10. Abbreviations

Acronym	Description
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
N-CDMA	Narrowband Code Division Multiple Access
PAR	Peak-to-Average power Ratio
RF	Radio Frequency
SMD	Surface Mounted Device
VSWR	Voltage Standing-Wave Ratio
WiMAX	Worldwide Interoperability for Microwave Access

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLF6G27-45_BLF6G27S-45#5	20150901	Product data sheet	-	BLF6G27-45_BLF6G27S-45 v.4	
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. Legal texts have been adapted to the new company name where appropriate. 				
BLF6G27-45_BLF6G27S-45 v.4	20130307	Product data sheet	-	BLF6G27-45_BLF6G27S-45_3	
BLF6G27-45_BLF6G27S-45_3	20081215	Product data sheet	-	BLF6G27-45_BLF6G27S-45_2	
BLF6G27-45_BLF6G27S-45_2	20080207	Preliminary data sheet		BLF6G27-45_BLF6G27S-45_1	
BLF6G27-45_BLF6G27S-45_1	20080129	Preliminary data sheet			

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12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
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WiMAX power LDMOS transistor

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WiMAX power LDMOS transistor

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